



**OPTIMIZED SOI
WAFER SOLUTIONS
FOR MEMS, RF AND
POWER DEVICES**

MORE DESIGN FREEDOM WITH BONDED SOI WAFERS

BSOI

Fully customizable with thick or thin device layer. Suitable e.g. for traditional MEMS and BCD devices. Also advanced options such as two device and BOX layers of different thicknesses.

E-SOI®

Highly uniform wafers with $\pm 0.1 \mu\text{m}$ thickness variation. Suitable e.g. for silicon photonics, high-precision silicon-based MEMS and BCD devices.

C-SOI®

Wafers with embedded / buried cavities. Suitable e.g. for pressure and inertial sensors, silicon speakers, ultrasonic transducers, resonators and microfluidic devices.

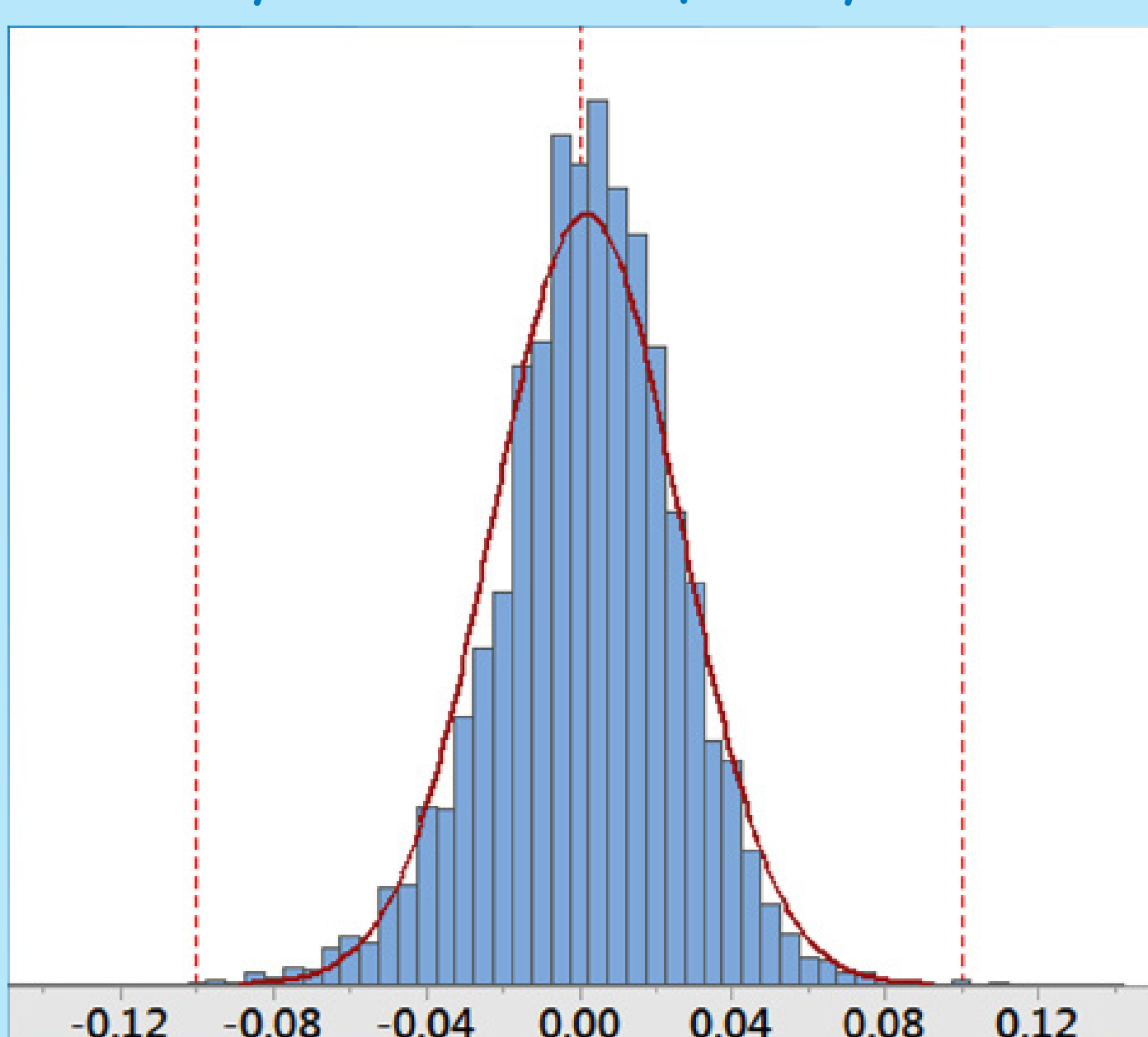
TSV – Through Silicon Vias

Polysilicon filled TSVs enable isolated electrical connections to be made through silicon wafers.

DESIGN FREEDOM, PERFORMANCE AND EASE OF MANUFACTURING

- Bonded SOI wafers provide an optimal platform for the manufacture of demanding MEMS, sensor, RF and power devices.
- Device manufacturers benefit from increased design freedom, maximum device performance, cost-effectiveness and ease of manufacturing.
- Customized wafer solutions to meet your device and process needs.
- SOI wafer volume production for leading semiconductor device manufacturers since 2001.
- Fully in-house process covering crystal growth, wafering, SOI bonding, DRIE and lithography.

Device layer thickness capability of E-SOI® wafers



Deviation from target thickness (μm)

TYPICAL SOI WAFER SPECIFICATIONS

RESISTIVITY

From < 0.001 to $> 7,000 \text{ Ohm-cm}$

DEVICE LAYER THICKNESS

From $1 \mu\text{m}$ to $> 200 \mu\text{m}$

Tolerance $\pm 0.5 \mu\text{m}$ (standard BSOI), $\pm 0.1 \mu\text{m}$ (200 mm E-SOI®), $\pm 0.5 \mu\text{m}$ (C-SOI®)

HANDLE WAFER THICKNESS

From $300 \mu\text{m}$ to $950 \mu\text{m}$, typically $725 \mu\text{m}$ in 200 mm wafer and $380 \mu\text{m}$ in 150 mm

Back surface polished or etched

BURIED OXIDE

Type: thermal oxide, thickness: from 300 nm to $4 \mu\text{m}$, typically between $0.5 \mu\text{m}$ and $2 \mu\text{m}$

